Operational Amplifier, Railto-Rail Output, 3 MHz BW

The NCx2007x series operational amplifiers provide rail-to-rail output operation, 3 MHz bandwidth, and are available in single, dual, and quad configurations. Rail-to-rail operation enables the user to make optimal use of the entire supply voltage range while taking advantage of 3 MHz bandwidth. The NCx2007x can operate on supply voltages as low as 2.7 V over the temperature range of -40° C to 125°C. At a 2.7 V supply, the high bandwidth provides a slew rate of 2.8 V/µs while only consuming 405 µA of quiescent current per channel. The wide supply range allows the NCx2007x to run on supply voltages as high as 36 V, making it ideal for a broad range of applications. Since this is a CMOS device, high input impedance and low bias currents make it ideal for interfacing to a wide variety of signal sensors. The NCx2007x devices are available in a variety of compact packages. Automotive qualified options are available under the NCV prefix.

Features

- Rail-To-Rail Output
- Wide Supply Range: 2.7 V to 36 V
- Wide Bandwidth: 3 MHz typical at $V_S = 2.7 V$
- High Slew Rate: 2.8 V/ μ s typical at V_S = 2.7 V
- Low Supply Current: 405 μ A per channel at V_S = 2.7 V
- Low Input Bias Current: 5 pA typical
- Wide Temperature Range: -40°C to 125°C
- Available in a variety of packages
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- Current Sensing
- Signal Conditioning
- Automotive

End Products

- Notebook Computers
- Portable Instruments
- Power Supplies



SOIC-14 NB CASE 751A

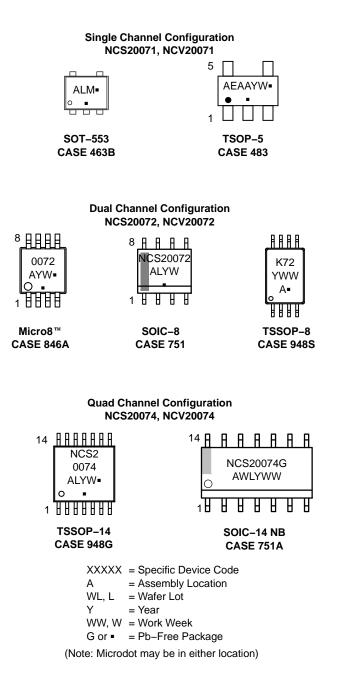
DEVICE MARKING INFORMATION

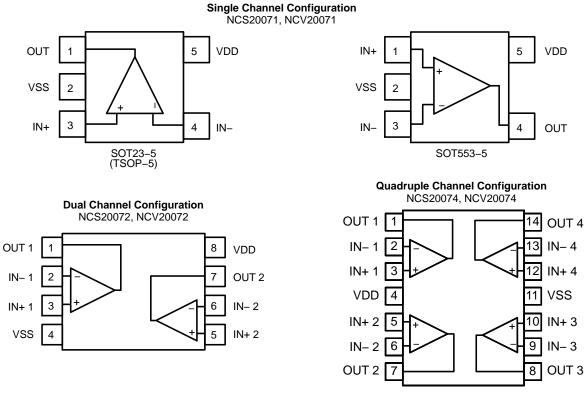
See general marking information in the device marking section on page 2 of this data sheet.

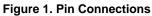
ORDERING INFORMATION

See detailed ordering and shipping information on page 4 of this data sheet.

MARKING DIAGRAMS







ORDERING INFORMATION

Device	Configuration	Automotive	Marking	Package	Shipping [†]
NCS20071SN2T1G			AEA	TSOP-5 (Pb-Free)	3000 / Tape and Reel
NCS20071XV53T2G	Obsela	No	AL	SOT553–5 (Pb–Free)	4000 / Tape and Reel
NCV20071SN2T1G*	- Single	No. a	AEA	TSOP-5 (Pb-Free)	3000 / Tape and Reel
NCV20071XV53T2G*		Yes	AL	SOT553–5 (Pb–Free)	4000 / Tape and Reel
NCS20072DMR2G			0072	Micro8 (MSOP8) (Pb–Free)	4000 / Tape and Reel
NCS20072DR2G		No	NCS20072	SOIC-8 (Pb-Free)	2500 / Tape and Reel
NCS20072DTBR2G	Durk		K72	TSSOP-8 (Pb-Free)	2500 / Tape and Reel
NCV20072DMR2G*	— Dual	Yes	0072	Micro8 (MSOP8) (Pb–Free)	4000 / Tape and Reel
NCV20072DR2G*			NCS20072	SOIC-8 (Pb-Free)	2500 / Tape and Reel
NCV20072DTBR2G*			K72	TSSOP-8 (Pb-Free)	2500 / Tape and Reel
NCS20074DR2G		Ne	NCS20074	SOIC-14 (Pb-Free)	2500 / Tape and Reel
NCS20074DTBR2G	Quad	No	NCS2 0074	TSSOP-14 (Pb-Free)	2500 / Tape and Reel
NCV20074DR2G*	Quad	No. 1	NCS20074	SOIC-14 (Pb-Free)	2500 / Tape and Reel
NCV20074DTBR2G*	7	Yes	NCS2 0074	TSSOP-14 (Pb-Free)	2500 / Tape and Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
 *NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP

Capable.

ABSOLUTE MAXIMUM RATINGS (Note 1)

	Rating	Symbol	Limit	Unit
Supply Voltage (V _{DD} – V _{SS}) (Note 4)	VS	40	V
Input Voltage		V _{CM}	V_{SS} – 0.2 to V_{DD} + 0.2	V
Differential Input Voltage (N	lote 2)	te 2) V _{ID} ±V _s		V
Maximum Input Current		I _{IN}	±10	mA
Maximum Output Current (Note 3)	Ι _Ο	±100	mA
Continuous Total Power Dis	ssipation (Note 4)	PD	200 m	
Maximum Junction Temper	ature	TJ	150	°C
Storage Temperature Rang	le	T _{STG}	-65 to 150	°C
Mounting Temperature (Infr	rared or Convection – 20 sec)	T _{mount}	260	°C
ESD Capability (Note 5)	Human Body Model Machine Model – NCx20071 Machine Model – NCx20072, NCx20074 Charged Device Model – NCx20071, NCx20072 Charged Device Model – NCx20074	HBM MM CDM CDM	2000 200 150 2000 (C6) 1000 (C6)	V
Latch–Up Current (Note 6)		I _{LU}	100	mA
Moisture Sensitivity Level (Note 7)	MSL	Level 1	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.

- 2. Maximum input current must be limited to ±10 mA. Series connected resistors of at least 500 Ω on both inputs may be used to limit the maximum input current to ±10 mA.
- 3. Total power dissipation must be limited to prevent the junction temperature from exceeding the 150°C limit.
- 4. Continuous short circuit operation to ground at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C. Output currents in excess of the maximum output current rating over the long term may adversely affect reliability. Shorting output to either VDD or VSS will adversely affect reliability.
- 5. This device series incorporates ESD protection and is tested by the following methods: ESD Human Body Model tested per JEDEC standard JS-001 (AEC-Q100-002) ESD Machine Model tested per JEDEC standard JESD22-A115 (AEC-Q100-003) ESD Charged Device Model tested per JEDEC standard JESD22-C101 (AEC-Q100-011)
- 6. Latch-up Current tested per JEDEC standard JESD78 (AEC-Q100-004) 7. Moisture Sensitivity Level tested per IPC/JEDEC standard J-STD-020A

THERMAL INFORMATION

Parameter	Symbol	Package	Single Layer Board (Note 8)	Multi–Layer Board (Note 9)	Unit
		SOT23-5 / TSOP5	265	195	
		SOT553-5	325	244	
		Micro8 / MSOP8	236	167	
Junction-to-Ambient	θ_{JA}	SOIC-8	190	131	°C/W
		TSSOP-8	253	194	
		SOIC-14	142	101	
		TSSOP-14	179	128	

8. Values based on a 1S standard PCB according to JEDEC51-3 with 1.0 oz copper and a 300 mm² copper area

9. Values based on a 1S2P standard PCB according to JEDEC51-7 with 1.0 oz copper and a 100 mm² copper area

OPERATING RANGES

Parameter	Symbol	Min	Max	Unit
Operating Supply Voltage (Single Supply)	VS	2.7	36	V
Operating Supply Voltage (Split Supply)	VS	±1.35	±18	V
Differential Input Voltage (Note 10)	V _{ID}		Vs	V
Input Common Mode Voltage Range	V _{CM}	V _{SS}	V _{DD} – 1.35	V
Ambient Temperature	T _A	-40	125	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

10. Maximum input current must be limited to ±10 mA. See Absolute Maximum Ratings for more information.

ELECTRICAL CHARACTERISTICS AT $V_S = 2.7 V$

 $T_A = 25^{\circ}C$; $R_L \ge 10 \text{ k}\Omega$; $V_{CM} = V_{OUT}$ = mid-supply unless otherwise noted. All limits are guaranteed by testing or statistical analysis. **Boldface** limits apply over the specified temperature range, $T_A = -40^{\circ}C$ to 125°C. (Notes 11, 12)

Parameter	Symbol	C	onditions	Min	Тур	Max	Unit
INPUT CHARACTERISTICS							
			NCv20071		1.3	±3.5	
Innut Offeet Veltere	N	ľ	NCx20071			±4.5	mV
Input Offset Voltage	V _{OS}		072, NCx20074		1.3	±3	IIIV
		NCX20	072, NCX20074			±4	1
Offset Voltage Drift	$\Delta V_{OS} / \Delta T$	$T_A = 25^{\circ}C$ to $125^{\circ}C$			2		μV/°C
Input Bias Current (Note 12)	lus –				5	200	nA
input bias Current (Note 12)	Ι _{IB}					1500	рА
		NCx20071, NCx20072			2	75	
	I _{OS} —					500	n A
Input Offset Current (Note 12)		NCx20074			2	75	рА
						200	
Channel Separation	XTLK	DC	NCx20072		100		dB
Channel Separation	AILK	DC	NCx20074		115		uв
Differential Input Resistance	R _{ID}				5		GΩ
Common Mode Input Resistance	R _{IN}				5		GΩ
Differential Input Capacitance	C _{ID}				1.5		pF
Common Mode Input Capacitance	C _{CM}				3.5		pF
Common Mode Rejection Ratio	CMRR	V_{CM} = V_{SS} + 0.2 V to V_{DD} – 1.35 V		90	110		dD
ommon Mode Rejection Ratio	CIVIKK			69			dB

OUTPUT CHARACTERISTICS

Open Loop Voltage Gain	A		96	118		dB
Open Loop Voltage Gain	A _{VOL}		86			uВ
Output Current Capability (Note 13)		Op amp sinking current		70		
	I _O	Op amp sourcing current		50		mA
Output) (oltogo ligh	V	Voltage output output from positive roll		0.006	0.15	V
Output Voltage High	V _{ОН}	Voltage output swing from positive rail			0.22	v
	M	Voltage output output from pagetive roll		0.005	0.15	V
Output Voltage Low	V _{OL}	Voltage output swing from negative rail			0.22	v

AC CHARACTERISTICS

Unity Gain Bandwidth	UGBW	C _L = 25 pF		3	MHz
Slew Rate at Unity Gain	SR	C_L = 20 pF, R_L = 2 k Ω		2.8	V/μs
Phase Margin	φm	C _L = 25 pF		50	0
Gain Margin	A _m	C _L = 25 pF		14	dB
Cottling Time		V _O = 1 Vpp,	Settling time to 0.1%	0.6	
Settling Time	t _S	$V_O = 1 Vpp,$ Gain = 1, C _L = 20 pF	Settling time to 0.01%	1.2	μs

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

11. Refer to ABSOLUTE MAXIMUM RATINGS and APPLICATION INFORMATION for Safe Operating Area.

12. Performance guaranteed over the indicated operating temperature range by design and/or characterization.

ELECTRICAL CHARACTERISTICS AT V_S = 2.7 V

 $T_A = 25^{\circ}C$; $R_L \ge 10 \text{ k}\Omega$; $V_{CM} = V_{OUT} = \text{mid-supply}$ unless otherwise noted. All limits are guaranteed by testing or statistical analysis. **Boldface** limits apply over the specified temperature range, $T_A = -40^{\circ}C$ to $125^{\circ}C$. (Notes 11, 12)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
NOISE CHARACTERISTICS						
Total Harmonic Distortion plus Noise	THD+N	$V_{IN} = 0.5 \text{ Vpp}, \text{ f} = 1 \text{ kHz}, \text{ Av} = 1$		0.05		%
han at Data and Malta an Alaba		f = 1 kHz		30		nV/√ Hz
Input Referred Voltage Noise	e _n	f = 10 kHz		20		
Input Referred Current Noise	i _n	f = 1 kHz		90		fA/√Hz
SUPPLY CHARACTERISTICS						

SUPPLY CHARACTERISTICS

Power Supply Rejection Ratio	PSRR	No L	ood	114	135		dB
	FORK		Juan	100			uВ
		NCx20071	No load		420	625	
			NO IOAU			765	
Power Supply Quiescent Current	IDD	NCv20072 NCv20074	Der channel no lood		405	525	μΑ
		NCx20072, NCx20074	Per channel, no load			625	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

11. Refer to ABSOLUTE MAXIMUM RATINGS and APPLICATION INFORMATION for Safe Operating Area.

12. Performance guaranteed over the indicated operating temperature range by design and/or characterization.

13. Power dissipation must be limited to prevent junction temperature from exceeding 150°C. See Absolute Maximum Ratings for more information.

ELECTRICAL CHARACTERISTICS AT V_S = 5 V

 $T_A = 25^{\circ}C$; $R_L \ge 10 \text{ k}\Omega$; $V_{CM} = V_{OUT} = \text{mid-supply unless otherwise noted}$. All limits are guaranteed by testing or statistical analysis. **Boldface** limits apply over the specified temperature range, $T_A = -40^{\circ}C$ to $125^{\circ}C$. (Notes 14, 15)

Parameter	Symbol	Conditions		Min	Тур	Max	Unit
INPUT CHARACTERISTICS							
			10-00074		1.3	±3.5	
land Offerst Vielterer		NCx20071				±4.5	
Input Offset Voltage	V _{os}	NO	070 NO.00074		1.3	±3	mV
		NCx20072, NCx20074				±4	
Offset Voltage Drift	$\Delta V_{OS} / \Delta T$	$T_A = 2$	25°C to 125 °C		2		μV/°C
Innut Ding Current (Nate 45)					5	200	- 0
Input Bias Current (Note 15)	I _{IB}					1500	рА
		NCx20071, NCx20072			2	75	рА
land offend Oursent (Ninter 45)						500	
Input Offset Current (Note 15)	los				2	75	
		r	VCx20074			200	1
	VTLK	50	NCx20072		100		10
Channel Separation	XTLK	DC	NCx20074		115		dB
Differential Input Resistance	R _{ID}				5		GΩ
Common Mode Input Resistance	R _{IN}				5		GΩ
Differential Input Capacitance	C _{ID}				1.5		pF
Common Mode Input Capacitance	C _{CM}				3.5		pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

14. Refer to ABSOLUTE MAXIMUM RATINGS and APPLICATION INFORMATION for Safe Operating Area.

15. Performance guaranteed over the indicated operating temperature range by design and/or characterization.

ELECTRICAL CHARACTERISTICS AT $V_S = 5 V$

 $T_A = 25^{\circ}C$; $R_L \ge 10 \text{ k}\Omega$; $V_{CM} = V_{OUT} = \text{mid-supply unless otherwise noted}$. All limits are guaranteed by testing or statistical analysis. **Boldface** limits apply over the specified temperature range, $T_A = -40^{\circ}C$ to $125^{\circ}C$. (Notes 14, 15)

Parameter	Symbol	Cond	litions	Min	Тур	Max	Unit
INPUT CHARACTERISTICS							
	01/22			102	125		
Common Mode Rejection Ratio	CMRR	$V_{CM} = V_{SS} + 0.2$	V to V _{DD} – 1.35 V	80			dB
OUTPUT CHARACTERISTICS						-	-
Onen Leen Valtere Coin	•			96	120		٦D
Open Loop Voltage Gain	A _{VOL}			86			dB
Output Current Conshility (Note 16)	1	Op amp sin	king current		50		
Output Current Capability (Note 16)	lo	Op amp sou	rcing current		60		mA
Output Voltage High	Maria		na from positivo roil		0.013	0.20	v
Output Voltage High	V _{OH}	voltage output swi	ng from positive rail			0.25	V
Output Voltage Low	V.		ng from negative rail		0.01	0.10	v
Oulput voltage Low	V _{OL}	voltage output swir	ig nom negative rail			0.15	V
AC CHARACTERISTICS							
Unity Gain Bandwidth	UGBW	C _L = 25 pF			3		MHz
Slew Rate at Unity Gain	SR	C _L = 20 pF	$R_L = 2 k\Omega$		2.7		V/μs
Phase Margin	ϕ_{m}	C _L =	25 pF		50		0
Gain Margin	A _m	C _L =	25 pF		14		dB
Settling Time	+	V _O = 3 Vpp,	Settling time to 0.1%		1.2		
Setting Time	t _S	Gain = 1, C_L = 20 pF	Settling time to 0.01%		5.6		μs
NOISE CHARACTERISTICS							
Total Harmonic Distortion plus Noise	THD+N	V _{IN} = 2.5 Vpp, f	ⁱ = 1 kHz, Av = 1		0.009		%
Input Referred Voltage Noise		f = 1	kHz		30		nV/√Hz
input Referred voltage Noise	e _n	f = 10	0 kHz		20		
Input Referred Current Noise	i _n	f = 1	kHz		90		fA/√Hz
SUPPLY CHARACTERISTICS							
Dowor Supply Poinction Potic	PSRR	No	Load	114	135		dB
Power Supply Rejection Ratio	PORK		Luau	100			uВ
		NCv20071	No load		430	635	
Power Supply Quiescont Current		NCx20071	100 1080			775	
Power Supply Quiescent Current	I _{DD}				410	530	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Per channel, no load

NCx20072, NCx20074

630

14. Refer to ABSOLUTE MAXIMUM RATINGS and APPLICATION INFORMATION for Safe Operating Area.

15. Performance guaranteed over the indicated operating temperature range by design and/or characterization.

ELECTRICAL CHARACTERISTICS AT $V_S = 10 V$

 $T_A = 25^{\circ}C$; $R_L \ge 10 \text{ k}\Omega$; $V_{CM} = V_{OUT}$ = mid-supply unless otherwise noted. All limits are guaranteed by testing or statistical analysis. Boldface limits apply over the specified temperature range, $T_A = -40^{\circ}C$ to 125°C. (Notes 17, 18)

Parameter	Symbol	C	onditions	Min	Тур	Max	Unit
INPUT CHARACTERISTICS							
Input Offeet Veltage	V	N	10,20071		1.3	±3.5	mV
Input Offset Voltage	V _{OS} NCx20071				±4.5	mV	
Input Offset Voltage	Vaa		072, NCx20074		1.3	±3	mV
input Onset voltage	V _{OS}	NCX20	072, NCX20074			±4	mV
Offset Voltage Drift	$\Delta V_{OS} / \Delta T$	$T_A = 25^{\circ}C$ to $125^{\circ}C$			2		μV/°C
Input Bias Current (Note 18)	l				5	200	pА
input bias current (Note 18)	I _{IB}	3				1500	рд
and Officer Coursest (Nate 40)		NCx20071, NCx20072			2	75	рА
						500	
Input Offset Current (Note 18)	los	NCx20074			2	75	
						200	
Channel Separation	XTLK	DC	NCx20072		100		dB
Channel Separation	AILK	DC	NCx20074		115		uБ
Differential Input Resistance	R _{ID}				5		GΩ
Common Mode Input Resistance	R _{IN}				5		GΩ
Differential Input Capacitance	C _{ID}				1.5		pF
Common Mode Input Capacitance	C _{CM}				3.5		pF
	01400			110	130		dB
Common Mode Rejection Ratio	CMRR	$v_{CM} = v_{SS} +$	$I = V_{SS} + 0.2 \text{ V to } V_{DD} - 1.35 \text{ V}$				uВ

OUTPUT CHARACTERISTICS

Open Loop Voltage Gain	٨		98	120		dB	
Open Loop voltage Gain	A _{VOL}		88			uБ	
Output Current Capability (Note 19)	1	Op amp sinking current		50			
	ι _Ο	Op amp sourcing current	65			mA	
Output Valtage Ligh	V _{OH}	Voltage output output from positive roll		0.023	0.08	V	
Output Voltage High		Voltage output swing from positive rail			0.10	v	
	V _{OL}			0.022	0.3	V	
Output Voltage Low		Voltage output swing from negative rail			0.35	v	

AC CHARACTERISTICS

Unity Gain Bandwidth	UGBW	C _L = 25 pF		3	MHz
Slew Rate at Unity Gain	SR	$C_L = 20 \text{ pF}, R_L = 2 \text{ k}\Omega$		2.6	V/μs
Phase Margin	φm	C _L = 25 pF		50	0
Gain Margin	A _m	C _L = 25 pF		14	dB
Cottling Time		V _O = 8.5 Vpp,	Settling time to 0.1%	3.4	
Settling Time	t _S	$V_O = 8.5 Vpp,$ Gain = 1, C _L = 20 pF	Settling time to 0.01%	6.8	μs

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

17. Refer to ABSOLUTE MAXIMUM RATINGS and APPLICATION INFORMATION for Safe Operating Area.

18. Performance guaranteed over the indicated operating temperature range by design and/or characterization.

ELECTRICAL CHARACTERISTICS AT V_S = 10 V

 $T_A = 25^{\circ}C$; $R_L \ge 10 \text{ k}\Omega$; $V_{CM} = V_{OUT} = \text{mid-supply}$ unless otherwise noted. All limits are guaranteed by testing or statistical analysis. Boldface limits apply over the specified temperature range, $T_A = -40^{\circ}C$ to 125°C. (Notes 17, 18)

Parameter	Symbol	I Conditions		Тур	Max	Unit
NOISE CHARACTERISTICS						
Total Harmonic Distortion plus Noise	THD+N	V _{IN} = 7.5 Vpp, f = 1 kHz, Av = 1		0.004		%
Input Referred Voltage Noise		f = 1 kHz	f = 1 kHz			nV/√ Hz
	e _n	f = 10 kHz		20		nv/√Hz
Input Referred Current Noise	i _n	f = 1 kHz		90		fA/√Hz
SUPPLY CHARACTERISTICS						

SUPPLY CHARACTERISTICS

Power Supply Rejection Ratio	PSRR	No Load		114	135		dB
	FORK		100			uВ	
Power Supply Quiescent Current		NCx20071	No load		430	645	
						785	
	IDD		Denskarsel verkend		416	540	μΑ
		NCx20072, NCx20074	Per channel, no load			640	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

17. Refer to ABSOLUTE MAXIMUM RATINGS and APPLICATION INFORMATION for Safe Operating Area.

18. Performance guaranteed over the indicated operating temperature range by design and/or characterization.

19. Power dissipation must be limited to prevent junction temperature from exceeding 150°C. See Absolute Maximum Ratings for more information.

ELECTRICAL CHARACTERISTICS AT V_S = 36 V

 $T_A = 25^{\circ}C$; $R_L \ge 10 \text{ k}\Omega$; $V_{CM} = V_{OUT} = \text{mid-supply unless otherwise noted}$. All limits are guaranteed by testing or statistical analysis. Boldface limits apply over the specified temperature range, $T_A = -40^{\circ}C$ to $125^{\circ}C$. (Notes 20, 21)

Parameter	Symbol	Conditions		Min	Тур	Max	Unit
INPUT CHARACTERISTICS							
	V _{os}	NCx20071			1.3	±3.5	mV
Innut Offert Veltere						±4.5	mV
Input Offset Voltage		NCv20	NCx20072, NCx20074		1.3	±3	mV
		NGA20072, NGA20074				±4	mV
Offset Voltage Drift	$\Delta V_{OS} / \Delta T$	$T_A = 25^{\circ}C$ to $125^{\circ}C$			2		μV/°C
					5	200	
Input Bias Current (Note 21)	I _{IB}	NCx20	071, NCx20072			2000	pА
		1	NCx20074			1500	
		NCx20071, NCx20072			2	75	
lanut Offerst Comment (Nister 24)						1000	
Input Offset Current (Note 21)	l _{os}		10.00074		2	75	рА
		ľ	NCx20074			200	1
	VTLK	50	NCx20072		100		JD
Channel Separation	XTLK	DC	NCx20074		115		dB
Differential Input Resistance	R _{ID}				5		GΩ
Common Mode Input Resistance	R _{IN}				5		GΩ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

20. Refer to ABSOLUTE MAXIMUM RATINGS and APPLICATION INFORMATION for Safe Operating Area.

21. Performance guaranteed over the indicated operating temperature range by design and/or characterization.

ELECTRICAL CHARACTERISTICS AT V_S = 36 V $T_A = 25^{\circ}C$; $R_L \ge 10 \text{ k}\Omega$; $V_{CM} = V_{OUT} = \text{mid-supply unless otherwise noted}$. All limits are guaranteed by testing or statistical analysis. Boldface limits apply over the specified temperature range, $T_A = -40^{\circ}C$ to 125°C. (Notes 20, 21)

Parameter	Symbol	Conc	ditions	Min	Тур	Max	Unit
INPUT CHARACTERISTICS							
Differential Input Capacitance	C _{ID}				1.5		pF
Common Mode Input Capacitance	C _{CM}				3.5		pF
		NCx20071	$V_{CM} = V_{SS} + 0.2 \text{ V to}$ $V_{DD} - 1.35 \text{ V}$	118	135		
			V _{DD} – 1.35 V	95			
Common Made Dejection Datio	01455	NO 00070	$V_{CM} = V_{SS} + 0.2 V to$	120	145		dB
Common Mode Rejection Ratio	CMRR	NCx20072	V _{DD} – 1.35 V	95			αв
	٦	NCx20074	$V_{CM} = V_{SS} + 0.2 \text{ V to}$ $V_{DD} - 1.35 \text{ V}$	120	145]
		V _{DD}	V _{DD} – 1.35 V	85			

OUTPUT CHARACTERISTICS

	٨			98	120		dB
Open Loop Voltage Gain	A _{VOL}			88			uБ
Output Current Capability (Note 22)	l.	Op amp sir	king current		50		mA
Supur Current Capability (Note 22)	Ι _Ο	Op amp sou	ircing current		65		IIIA
	V _{OH}		NCx20071		0.074	0.15	
		Voltage output swing from positive rail	INCX20071			0.22	
Output Valtage Ligh			NCx20072		0.074	0.10	N
Output Voltage High						0.15	V
			NCx20074		0.074	0.10	
						0.12	
					0.065	0.3	V
Output Voltage Low	V _{OL}	Voltage output swing from negative rail				0.35	v

AC CHARACTERISTICS

Unity Gain Bandwidth	UGBW	C _L = 25 pF		3		MHz
Slew Rate at Unity Gain	SR	$C_L = 20 \text{ pF}, R_L = 2 \text{ k}\Omega$		2.4		V/μs
Phase Margin	φm	C _L = 25 pF		50		0
Gain Margin	A _m	C _L = 25 pF		14		dB
Settling Time		V _O = 10 Vpp, Gain = 1, C _L = 20 pF	Settling time to 0.1%	3.2		μs
	t _S		Settling time to 0.01%	7		

NOISE CHARACTERISTICS

Total Harmonic Distortion plus Noise	THD+N V _{IN} = 28.5 Vpp, f = 1 kHz, Av = 1		0.001	%	
Input Referred Voltage Naise	<u>^</u>	f = 1 kHz	30	nV/√ Hz	
Input Referred Voltage Noise	e _n	f = 10 kHz	20		
Input Referred Current Noise	i _n	f = 1 kHz	90	fA/√Hz	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

20. Refer to ABSOLUTE MAXIMUM RATINGS and APPLICATION INFORMATION for Safe Operating Area.

21. Performance guaranteed over the indicated operating temperature range by design and/or characterization.

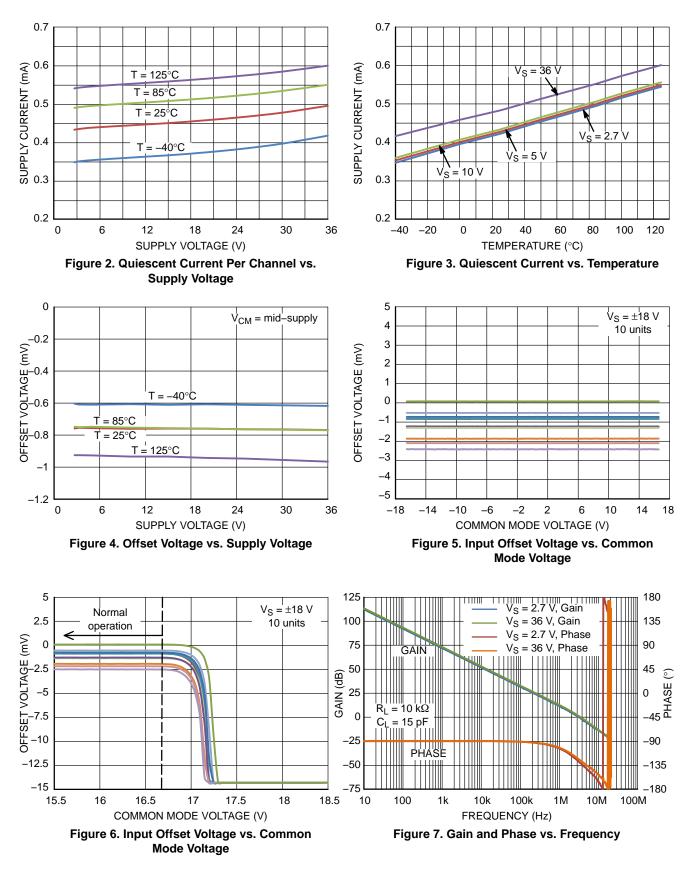
ELECTRICAL CHARACTERISTICS AT V_S = 36 V $T_A = 25^{\circ}C$; $R_L \ge 10 \text{ k}\Omega$; $V_{CM} = V_{OUT} = \text{mid-supply unless otherwise noted}$. All limits are guaranteed by testing or statistical analysis. Boldface limits apply over the specified temperature range, $T_A = -40^{\circ}C$ to 125°C. (Notes 20, 21)

Parameter	Symbol	Conditions		Min	Тур	Max	Unit
SUPPLY CHARACTERISTICS							
Dower Supply Dejection Datio	DODD	No Load		114	135		dB
Power Supply Rejection Ratio	PSRR	INO	100			uБ	
		NCx20071	No load		480	700	
			100 1080			840	
Device Complex Outlease at Compart	I _{DD}		Der ekennel as lead		465	570	
Power Supply Quiescent Current		NCx20072	Per channel, no load			700	μΑ
		NCx20074 Per channel, no load			465	600	
					700		

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

20. Refer to ABSOLUTE MAXIMUM RATINGS and APPLICATION INFORMATION for Safe Operating Area.

21. Performance guaranteed over the indicated operating temperature range by design and/or characterization.



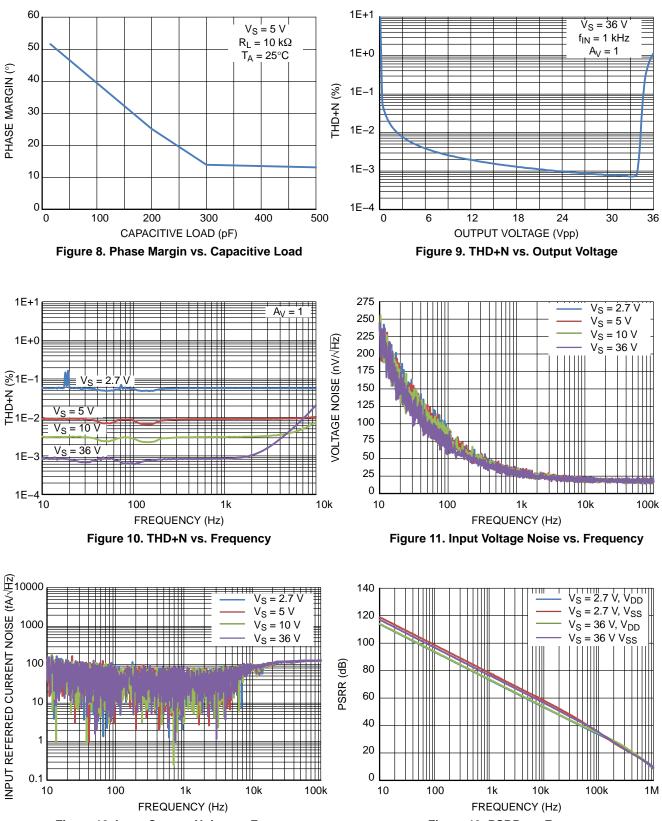
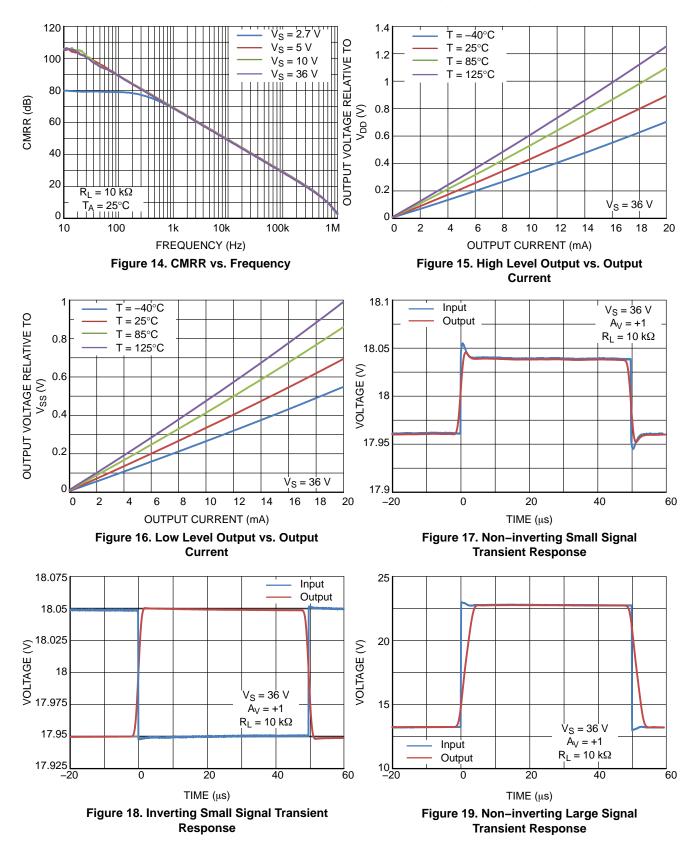
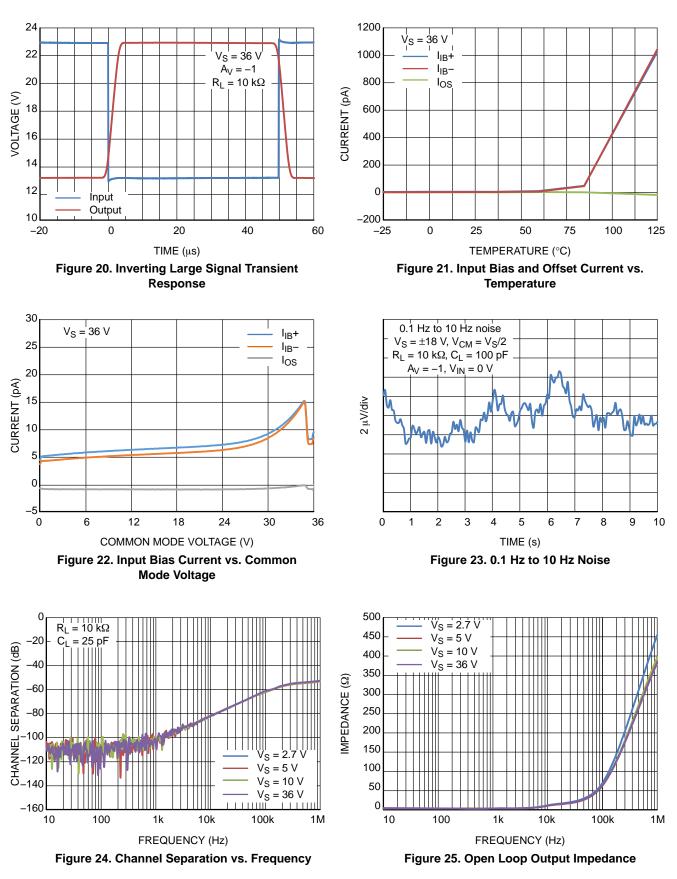


Figure 12. Input Current Noise vs. Frequency

Figure 13. PSRR vs. Frequency





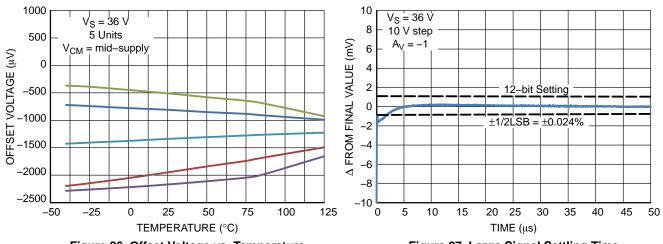
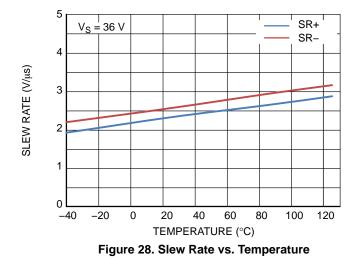


Figure 26. Offset Voltage vs. Temperature

Figure 27. Large Signal Settling Time



<u>www.onsemi.com</u> 17

APPLICATIONS INFORMATION

Input Circuit

The NCS2007x input stage has a PMOS input pair and ESD protection diodes. The input pair is internally connected by back–to–back Zener diodes with a reverse voltage of 5.5 V. To protect the internal circuitry, the input current must be limited to 10 mA. When operating the

NCS2007x at differential voltages greater than $V_{ID} = 26$ V, series resistors can be added externally to limit the input current flowing between the input pins. Adding 500 Ω resistors in series with the input prevents the current from exceeding 10 mA over the entire operating range up to 36 V.

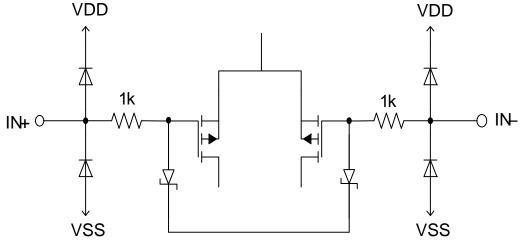


Figure 29. Differential Input Pair

Output

The NCS2007x has a class AB output stage with rail-to-rail output swing.

High output currents can cause the junction temperature to exceed the 150°C absolute maximum rating. In the case of a short circuit where the output is connected to either supply rail, the amount of current the op amp can source and sink is described by the output current capability parameter listed in the Electrical Characteristics. The junction temperature at a given power dissipation, P, can be calculated using the following formula:

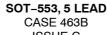
 $T_J = T_A + P \ x \ \theta_{JA}$

The thermal resistance between junction and ambient, θ_{JA} , is provided in the Thermal Information section of this datasheet.

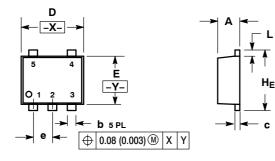




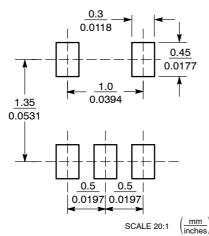
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ISSUE C



RECOMMENDED **SOLDERING FOOTPRINT***



NOTES:

NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETERS 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

	м	ILLIMETE	RS	INCHES				
DIM	MIN	NOM	MAX	MIN	NOM	MAX		
Α	0.50	0.55	0.60	0.020	0.022	0.024		
b	0.17	0.22	0.27	0.007	0.009	0.011		
С	0.08	0.13	0.18	0.003	0.005	0.007		
D	1.55	1.60	1.65	0.061	0.063	0.065		
E	1.15	1.20	1.25	0.045	0.047	0.049		
е		0.50 BSC			0.020 BSC)		
L	0.10	0.20	0.30	0.004	0.008	0.012		
HE	1.55	1.60	1.65	0.061	0.063	0.065		

GENERIC **MARKING DIAGRAM***

XXM-

XX = Specific Device Code M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:
PIN 1. BASE	PIN 1. CATHODE	PIN 1. ANODE 1	PIN 1. SOURCE 1	PIN 1. ANODE
2. EMITTER	2. COMMON ANODE	2. N/C	2. DRAIN 1/2	2. EMITTER
3. BASE	3. CATHODE 2	3. ANODE 2	3. SOURCE 1	3. BASE
4. COLLECTOR	4. CATHODE 3	4. CATHODE 2	4. GATE 1	4. COLLECTOR
5. COLLECTOR	5. CATHODE 4	5. CATHODE 1	5. GATE 2	5. CATHODE
STYLE 6:	STYLE 7:	STYLE 8:	STYLE 9:	
PIN 1. EMITTER 2	PIN 1. BASE	PIN 1. CATHODE	PIN 1. ANODE	
2. BASE 2	2. EMITTER	2. COLLECTOR	2. CATHODE	
3. EMITTER 1	3. BASE	3. N/C	3. ANODE	
4. COLLECTOR 1	4. COLLECTOR	4. BASE	4. ANODE	
5. COLLECTOR 2/BASE 1	5. COLLECTOR	5. EMITTER	5. ANODE	

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Α	ADDED STYLES 3–9. REQ. BY D. BARLOW	11 NOV 2003		
В	ADDED NOMINAL VALUES AND UPDATED GENERIC MARKING DIAGRAM. REQ. BY HONG XIAO	27 MAY 2005		
С	UPDATED DIMENSIONS D, E, AND HE. REQ. BY J. LETTERMAN.	20 MAR 2013		

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STYLE 1: PIN 1. EMITTER COLLECTOR 2. COLLECTOR 3. 4. EMITTER 5. EMITTER BASE 6. 7 BASE EMITTER 8. STYLE 5: PIN 1. DRAIN 2. DRAIN 3. DRAIN DRAIN 4. GATE 5. 6. GATE SOURCE 7. 8. SOURCE STYLE 9: PIN 1. EMITTER, COMMON COLLECTOR, DIE #1 COLLECTOR, DIE #2 2. З. EMITTER, COMMON 4. 5. EMITTER, COMMON 6 BASE. DIE #2 BASE, DIE #1 7. 8. EMITTER, COMMON STYLE 13: PIN 1. N.C. 2. SOURCE 3 GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. DRAIN 8. STYLE 17: PIN 1. VCC 2. V2OUT V10UT З. TXE 4. 5. RXE 6. VFF 7. GND 8. ACC STYLE 21: PIN 1. CATHODE 1 2. CATHODE 2 3 CATHODE 3 CATHODE 4 4. 5. CATHODE 5 6. COMMON ANODE COMMON ANODE 7. 8. CATHODE 6 STYLE 25: PIN 1. VIN 2 N/C REXT З. 4. GND 5. IOUT 6. IOUT IOUT 7. 8. IOUT STYLE 29: BASE, DIE #1 PIN 1. 2 EMITTER, #1 BASE, #2 З. EMITTER, #2 4. 5 COLLECTOR, #2

STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 COLLECTOR, #2 3. 4 COLLECTOR, #2 BASE, #2 5. EMITTER, #2 6. 7 BASE #1 EMITTER, #1 8. STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN SOURCE 4. SOURCE 5. 6. GATE GATE 7. 8. SOURCE STYLE 10: GROUND PIN 1. BIAS 1 OUTPUT 2. З. GROUND 4. 5. GROUND 6 BIAS 2 INPUT 7. 8. GROUND STYLE 14: PIN 1. N-SOURCE 2. N-GATE P-SOURCE 3 P-GATE 4. P-DRAIN 5 6. P-DRAIN N-DRAIN 7. N-DRAIN 8. STYLE 18: PIN 1. ANODE 2. ANODE SOURCE 3. GATE 4. 5. DRAIN 6 DRAIN CATHODE 7. CATHODE 8. STYLE 22 PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC 3 COMMON CATHODE/VCC 4. I/O LINE 3 5. COMMON ANODE/GND 6. I/O LINE 4 7. I/O LINE 5 8. COMMON ANODE/GND STYLE 26: PIN 1. GND 2 dv/dt З. ENABLE 4. ILIMIT 5. SOURCE SOURCE 6. SOURCE 7. 8. VCC STYLE 30: DRAIN 1 PIN 1. DRAIN 1 2 GATE 2 З. SOURCE 2 4. SOURCE 1/DRAIN 2 SOURCE 1/DRAIN 2 5. 6.

STYLE 3: PIN 1. DRAIN, DIE #1 DRAIN, #1 2. DRAIN, #2 З. 4. DRAIN, #2 GATE, #2 5. SOURCE, #2 6. 7 GATE #1 8. SOURCE, #1 STYLE 7: PIN 1. INPUT 2. EXTERNAL BYPASS THIRD STAGE SOURCE GROUND З. 4. 5. DRAIN 6. GATE 3 SECOND STAGE Vd 7. FIRST STAGE Vd 8. STYLE 11: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. DRAIN 2 DRAIN 1 7. 8. DRAIN 1 STYLE 15: PIN 1. ANODE 1 2. ANODE 1 ANODE 1 3 ANODE 1 4. 5. CATHODE, COMMON CATHODE, COMMON CATHODE, COMMON 6. 7. CATHODE, COMMON 8. STYLE 19: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. MIRROR 2 7. DRAIN 1 8. **MIRROR 1** STYLE 23: PIN 1. LINE 1 IN COMMON ANODE/GND COMMON ANODE/GND 2. 3 LINE 2 IN 4. LINE 2 OUT 5. COMMON ANODE/GND COMMON ANODE/GND 6. 7. LINE 1 OUT 8. STYLE 27: PIN 1. ILIMIT 2 OVI 0 UVLO З. 4. INPUT+ 5. SOURCE SOURCE 6. SOURCE 7. 8 DRAIN

DATE 16 FEB 2011

STYLE 4: PIN 1. 2. ANODE ANODE ANODE З. 4. ANODE ANODE 5. 6. ANODE 7 ANODE COMMON CATHODE 8. STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 BASE, #2 З. COLLECTOR, #2 4. COLLECTOR, #2 5. 6. EMITTER, #2 EMITTER, #1 7. 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE SOURCE 2. 3. GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 16: PIN 1. EMITTER, DIE #1 2. BASE, DIE #1 EMITTER, DIE #2 3 BASE, DIE #2 4. 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 COLLECTOR, DIE #1 7. COLLECTOR, DIE #1 8. STYLE 20: PIN 1. SOURCE (N) GATE (N) SOURCE (P) 2. 3. 4. GATE (P) 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 24: PIN 1. BASE 2. EMITTER 3 COLLECTOR/ANODE COLLECTOR/ANODE 4. 5. CATHODE 6. CATHODE COLLECTOR/ANODE 7. 8. COLLECTOR/ANODE STYLE 28: PIN 1. SW_TO_GND 2. DASIC OFF DASIC_SW_DET З. 4. GND 5. 6. V MON VBULK 7. VBULK 8 VIN

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SOURCE 1/DRAIN 2

7.

8. GATE 1

COLLECTOR, #2

COLLECTOR, #1

COLLECTOR, #1

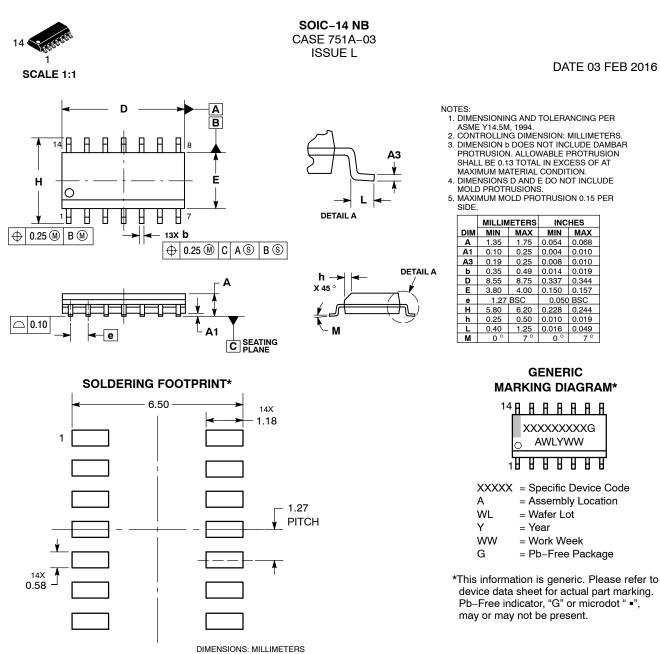
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DATE 03 FEB 2016

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STYLE 5: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 6: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE	STYLE 7: PIN 1. ANODE/CATHODE 2. COMMON ANODE 3. COMMON CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. COMMON CATHODE 12. COMMON ANODE 13. ANODE/CATHODE 14. ANODE/CATHODE	STYLE 8: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE

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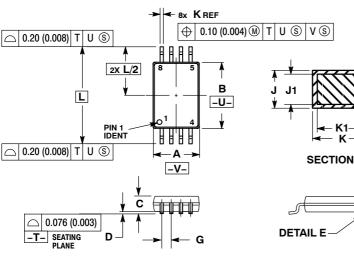
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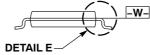


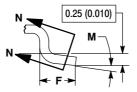
TSSOP-8 CASE 948S-01 ISSUE C

DATE 20 JUN 2008



SECTION N-N





DETAIL E

NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI

- VIMENSIONING AND TOLENANDING FER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
 DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH.
- PROTRUSION SHALL NOT EXCEED 0.15
 (0.006) PER SIDE.
 JIMENSION B DOES NOT INCLUDE INTERLEAD
 FLASH OR PROTRUSION. INTERLEAD FLASH OR
 PROTRUSION SHALL NOT EXCEED 0.25 (0.010)
 DED SIDE. PER SIDE
- 5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- 6. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	2.90	3.10	0.114	0.122
В	4.30	4.50	0.169	0.177
С		1.10		0.043
D	0.05	0.15	0.002	0.006
F	0.50	0.70	0.020	0.028
G	0.65	BSC	0.026 BSC	
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252	BSC
М	0 °	8°	0°	8 °

GENERIC **MARKING DIAGRAM***

0	XXX	
	YWW	
	A •	
	•	

XXX = Specific Device Code А

- = Assembly Location
- = Year

Y

- WW = Work Week
- = Pb-Free Package -

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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100115		DATE
ISSUE	REVISION	DATE
0	RELEASED FOR PRODUCTION.	18 APR 2000
А	ADDED MARKING DIAGRAM INFORMATION. REQ. BY V. BASS.	13 JAN 2006
В	CORRECTED MARKING DIAGRAM PIN 1 LOCATION AND MARKING. REQ. BY C. REBELLO.	13 MAR 2006
С	REMOVED EXPOSED PAD VIEW AND DIMENSIONS P AND P1. CORRECTED MARKING INFORMATION. REQ. BY C. REBELLO.	20 JUN 2008

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